A look-up table algorithm to model radiation damage effects in Monte Carlo events for HL-LHC experiments

M. Bomben and K. Nakkalil

CNRS APC and Université Paris Cité, 10 Rue Alice Domon et Léonie Duquet, 75013 Paris, France

E-mail: marco.bomben@cern.ch

ABSTRACT: Radiation damage significantly impacts the performance of silicon tracking detectors in Large Hadron Collider (LHC) experiments such as ATLAS and CMS, with signal reduction being the most critical effect. Adjusting sensor bias voltage and detection thresholds can help mitigate these effects, but generating simulated data that accurately mirror the performance evolution with the accumulation of luminosity, hence fluence, is crucial. The ATLAS collaboration has developed and implemented algorithms to correct simulated Monte Carlo (MC) events for radiation damage effects, achieving impressive agreement between collision data and simulated events. In preparation for the high-luminosity phase (HL-LHC), the demand for a faster ATLAS MC production algorithm becomes imperative due to escalating collision, events, tracks, and particle hit rates, imposing stringent constraints on available computing resources. This article outlines the philosophy behind the new algorithm, its implementation strategy, and the essential components involved. The results from closure tests indicate that the events simulated using the new algorithm agree with fully simulated events at the level of few %. The first tests on computing performance show that the new algorithm is as fast as it is when no radiation damage corrections are applied.

KEYWORDS: Solid state detectors, Performance of High Energy Physics Detectors, Simulation methods and programs

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1 Introduction

Hybrid silicon pixel modules are at the core of the tracking detectors in High Energy Physics (HEP) experiments at the CERN Large Hadron Collider (LHC), see for example [1, 2]. The fast hadrons produced by LHC *pp* collisions can displace Si atoms and hence create deep states in the Si energy band gap. These deep states are responsible at macroscopic level of the increase of leakage current, the change in operational voltage and decrease of signal amplitude [3]. Operating the detector cold, adjusting sensor bias voltage and readout electronics thresholds and calibrations assure high hit efficiency despite the declining charge collection efficiency (CCE). It is also important to have simulated events mimicking the evolution of CCE with the accumulation of luminosity, hence radiation damage fluence. The ATLAS collaboration developed and, since LHC Run 3, implemented algorithms [4] - the so called radiation damage digitizer - that starting from precise sensor electric field maps simulated using TCAD¹ tools can reproduce the evolution of cluster properties (charge, size) at % level of agreement with data [5].

The LHC accelerator will be upgraded to a High Luminosity machine (HL-LHC)² with instantaneous luminosity increasing by a factor of 3-5 with respect to LHC Run 3, with the goal to integrate over 10 years a dataset ten times larger than the one expected at the end of Run 3. The large increase in instantaneous luminosity will translate into much larger events, particles and hits rates, in particular for the detector closest to the interaction point, the pixel detector; radiation damage doses and fluence will increase too, by almost a factor 10. For these reasons the ATLAS collaboration is preparing an upgraded pixel detector, the Inner Tracker (ITk) Pixel Detector [6], capable to assure the same if not even better performance of the original Pixel Detector but in a much harsher environment.

The high luminosity phase of LHC will impose severe constraints also on computing resources. For example, despite the great performance of the radiation damage digitizer, it will have to be abandoned because it will be too demanding in terms of computing resources during the HL-LHC

¹Technology Computer Aided Design

²https://hilumilhc.web.cern.ch/content/hl-lhc-project

phase. In this paper a new lightweight algorithm for the radiation damage digitizer is presented. Its primary goal is to be as fast as possible, and to deliver precise predictions in terms of cluster charge and size as a function of the accumulated radiation damage. The algorithm is based on Look-Up tables (section 2), which are prepared combining TCAD and MC simulations (section 3). The new algorithm has been tested performing several closure tests (section 4). Section 5 will end the article.

2 Look-Up Table Method

In the original ATLAS radiation damage digitizer groupes of charge carriers produced by ionising particles are drifted towards the collecting electrodes, calculating their final position by integrating their movement based on electric field maps and mobility function; the signal amplitude on different pixel electrodes is then calculated using the Ramo theorem [7, 8]. As said in the introduction this algorithm makes very precise predictions but it is significantly slower than the standard one (i.e. without radiation damage). In the new proposed algorithm the complicate dynamics of carriers will be replaced by scalar values, stored in so called Look-Up Tables (LUTs). For a charge q deposited at depth z inside the sensor bulk the final signal amplitude q_{ind} and its final ("propagated") position $(x_{prop}, y_{prop}, z_{prop})$ will be calculate using three LUTs, one for the *CCE*, one for the free path Δz in z and one for the tangent of Lorentz angle $\theta_{LA}(z)$; all LUTs will indeed depend on the deposition depth z. The signal amplitude and the propagated position are calculated as detailed in eq. 2.1:

$$q_{ind} = CCE(z) * q,$$

$$x_{prop} = x + [\tan(\theta_{LA}(z)) \cdot \Delta z(z)] + \Delta^{diff}x$$

$$y_{prop} = y + \Delta^{diff}y$$

$$z_{prop} = z + \Delta z(z),$$
(2.1)

where $\Delta^{diff} x$, y is a Gaussian-distributed random number added to simulate the effect x, y of diffusion. More details on the method can be found in ref. [9].

3 LUT Creation

In order to create the three LUTs it is necessary to have a precise simulation of the signals created by ionising particles in pixel detectors. In this work the task was accomplished using the Allpix² MC simulation framework [10]. Within Allpix² the response to radiation of silicon detectors can be simulated with great detail, thanks to the possibility of controlling in a modular way all involved processes, from charge deposition to signal digitization and construction, including charge carrier propagation.

Using Allpix² it was possible to simulate events for a 150 µm thick n-on-p planar pixel sensors with a pitch of $50 \times 50 \ 150 \ \mu\text{m}^2$. The electric field profile map was taken from a TCAD simulation that included radiation damage effects corresponding to a fluence Φ of $1 \times 10^{15} \ n_{eq}/\text{cm}^2$; the TCAD model for radiation damage [11] developed by the LHCb collaboration was used. The Ramo potential map was calculated too using TCAD tools. The resulting LUTs are reported in Figure 1 for a bias voltage of $V_{bias} = 400 \text{ V}$.



Figure 1: (Left) LUTs for irradiated planar pixels, $(150 \,\mu\text{m thick}, 50 \times 50 \, 150 \,\mu\text{m}^2, \Phi = 1 \times 10^{15} \,\text{n}_{\text{eq}}/\text{cm}^2$, $V_{\text{bias}} = 400 \,\text{V}$). (top) CCE; (mid) tangent of Lorentz ange; (bottom) average free path.

(Right) Comparison of LUT and FS events at $\eta=1$. (top) cluster charge; (mid) transverse cluster size; (bottom) longitudinal cluster size.

From the CCE LUT is visible the effect of signal screening of holes in the region between pixel side $(0 \,\mu\text{m})$ and $20 \,\mu\text{m}$ away from it; at $80 \,\mu\text{m}$ from the pixel the free path is reduced to half; the largest deflection is of course expected from carriers produced at the backside.

4 Closure Tests

Lacking experimental data from irradiated pixel modules, a series of closures tests were conducted in order to validate the LUT method and ingredients. In particular, a comparison of events simulated

using the LUT method with Fully Simulated (FS) ones was performed. The distribution of cluster charge and cluster size in both projections - transverse and parallel to the magnetic field - were compared between LUT and FS events; more details in [9]. Here the results of a closure test for the device and conditions mentioned in sect. 3 are reported. The module was tilted at different angles with respect to the simulated π^+ beam to emulate the data-taking conditions in ATLAS. In figure 1 a comparison for pseudorapidity³ $\eta = 1$.

The level of agreement is remarkable for both projections of cluster size. LUT based events are characterised by an average cluster charge 10% larger than FS ones; this will be investigated. Overall the agreement can be considered satisfactory.

The study has been repeated for several η values. A relative difference ϵ as been calculated as:

$$\epsilon = \frac{\langle O \rangle_{LUT} - \langle O \rangle_{FS}}{\langle O \rangle_{FS}} \tag{4.1}$$

where $\langle O \rangle$ is the average value of the distribution of observable O which is either cluster cluster charge Q or transverse/longitudinal cluster size $CS_{X,Y}$. Results are reported in figure 2.



Figure 2: Relative percentage difference ϵ between LUT and FS events at different η values. For all observables ϵ is calculated as the difference between mean values of the observable distribution of LUT and FS events divided by the value of FS events.

The agreement in both projections of cluster size is at a few % level which is extremely promising; cluster charge is somewhat larger in LUT than FS events. At $\eta = 1.4$ the agreement for transverse cluster size is less optimal: this is similar to what reported in [9] for a different simulated sensor. The situation is being investigated.

5 Conclusions and Outlook

Radiation damage is the limiting effect of pixel detector performance at hadron colliders. In this paper a novel algorithm to include these effects in MC simulated events has been discussed. Closures tests indicate it is quite precise in reproducing cluster properties like charge and size. In a preliminary test on computing performance the production of simulated events using the LUT

 $^{{}^{3}\}eta = -\ln(\tan(\theta/2))$, where θ is the polar angle with respect to the direction of the beam

method was as fast as the basic version, i.e. without radiation damage. This was expected since the algorithmic complexity of the LUT algorithm is basically the same of the original one.

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